Integrated Load Switch

FDC6329L

Description

This device is particularly suited for compact power management in portable electronic equipment where 2.5 V to 8 V input and 2.5 A output current capability are needed. This load switch integrates a small N-Channel power MOSFET (Q1) which drives a large P-Channel power MOSFET (Q2) in one tiny SUPERSOTTM-6 package.

Features

- $V_{DROP} = 0.20 \text{ V } @ V_{IN} = 5 \text{ V}, I_L = 2.8 \text{ A}, R_{(on)} = 0.07 \Omega$
- $V_{DROP} = 0.20 \text{ V}$ @ $V_{IN} = 2.5 \text{ V}$, $I_L = 1.9 \text{ A}$, $R_{(on)} = 0.105 \Omega$
- Control MOSFET (Q1) Includes Zener Protection for ESD Ruggedness (> 6 kV Human Body Model)
- High Performance Trench Technology for Extremely Low On–Resistance
- SUPERSOT-6 Package Design Using Copper Lead Frame for Superior Thermal and Electrical Capabilities
- This is a Pb-Free and Halide Free Device

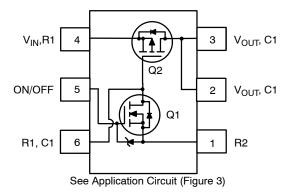


Figure 1.

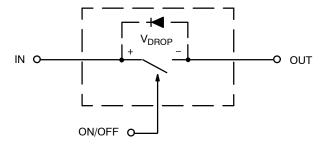


Figure 2. Equivalent Circuit



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TSOT-23-6 CASE 419BL

MARKING DIAGRAM



&E = Designates Space

&Y = Binary Calendar Year Coding Scheme

&. = Pin One Dot

329 = Specific Device Code

&G = Date Code

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------|------------------------|-----------------------|
| FDC6329L | TSOT-23-6 (Pb-Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

FDC6329L

ABSOLUTE MAXIMUM RATINGS T_A = 25°C unless otherwise noted

| Symbol | Parameter | Value | Unit |
|-----------------------------------|--|------------|------|
| V _{IN} | Input Voltage Range (Note 1) | 2.5-8 | V |
| V _{ON/OFF} | On/Off Voltage Range | 1.5–8 | V |
| ΙL | Load Current - Continuous (Note 2) | 2.5 | Α |
| | Load Current - Pulsed | 10 | 1 |
| P _D | Maximum Power Dissipation (Note 2) | 0.7 | W |
| T _J , T _{STG} | Operating and Storage Temperature Range | -55 to 150 | °C |
| ESD | Electrostatic Discharge Rating MIL-STD-883D Human Body Model (100 pF / 1500 Ω) | 6 | kV |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS $T_A = 25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Value | Unit |
|----------------|--|-------|------|
| $R_{	heta JA}$ | Thermal Resistance, Junction-to-Ambient (Note 2) | 180 | °C/W |
| $R_{	heta JC}$ | Thermal Resistance, Junction-to-Case (Note 2) | 60 | °C/W |

ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Тур | Max | Unit |
|---------------------|---------------------------------------|---|-----|-------|-------|------|
| OFF CHARACTERISTICS | | | | | | |
| I _{FL} | Forward Leakage Current | V _{IN} = 8 V, V _{ON/OFF} = 0 V | - | - | 1 | μΑ |
| ON CHARAC | TERISTICS (Note 3) | | | | | |
| V_{DROP} | Conduction Voltage | V _{IN} = 5 V, V _{ON/OFF} = 3.3 V, I _L = 2.8 A | - | 0.12 | 0.2 | V |
| | | V _{IN} = 2.5 V, V _{ON/OFF} = 3.3 V, I _L = 1.9 A | - | 0.14 | 0.2 | |
| R _{DS(on)} | Q ₂ – Static On–Resistance | $V_{GS} = -5 \text{ V}, I_D = -2.5 \text{ A}$ | - | 0.047 | 0.07 | Ω |
| | | V _{GS} = -2.5 V, I _D = -2.0 A | - | 0.073 | 0.105 | |
| ΙL | Load Current | V _{DROP} = 0.2 V, V _{IN} = 5 V, V _{ON/OFF} = 3.3 V | 2.8 | - | _ | Α |
| | | V _{DROP} = 0.2 V, V _{IN} = 2.5 V, V _{ON/OFF} = 3.3 V | 1.9 | - | _ | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 1. Range of V_{in} can be up to 8 V, but R_1 and R_2 must be scaled such that V_{GS} of Q2 does not exceed -8 V. 2. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

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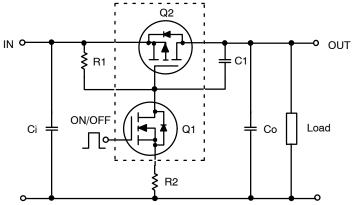


Figure 3. FDC6329L Load Switch Application

External Component Recommendation:

For applications where Co \leq 1 $\mu F.$ For slew rate control, select R2 in the range of 1k - 4.7 k $\Omega.$

For additional in–rush current control, C1 ≤ 1000 pF can be added.

Select R1 so that the R1/R2 ratio ranges from 10 - 100. R1 is required to turn Q2 off.

TYPICAL CHARACTERISTICS

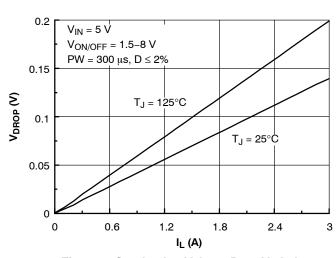


Figure 4. Conduction Voltage Drop Variation with Load Current

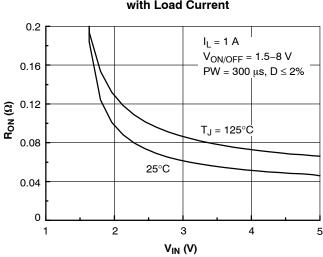


Figure 6. On-Resistance Variation with Input Voltage

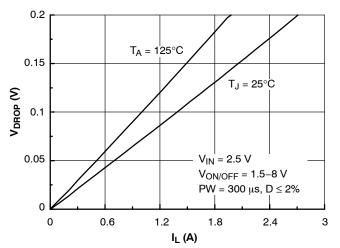


Figure 5. Conduction Voltage Drop Variation with Load Current

FDC6329L

TYPICAL CHARACTERISTICS (continued)

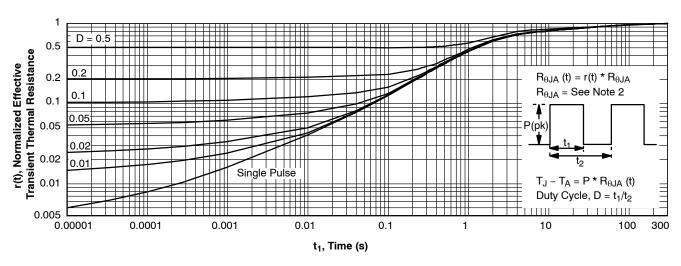


Figure 7. Transient Thermal Response Curve

NOTE: Thermal characterization performed on the conditions described in Note 2.

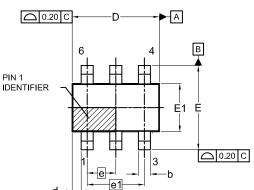
Transient thermal response will change depending on the circuit board design.

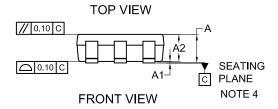
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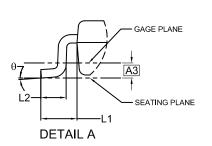


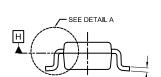
TSOT23 6-Lead CASE 419BL **ISSUE A**

DATE 31 AUG 2020









SIDE VIEW

03/1414

| SYMM |
|------------------|
| Ę |
| 0.95 |
| 1.00 MIN |
| 2.60 |
| |
| 0.70 MIN |

LAND PATTERN RECOMMENDATION

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- CONTROLLING DIMENSION: MILLIMETERS
 DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
 PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.25MM PER END. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
- 4. SEATING PLANE IS DEFINED BY THE TERMINALS. "A1" IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

| οιм | MILLIMETERS | | | |
|-------|-------------|------|------|--|
| 5,101 | MIN. | NOM. | MAX. | |
| Α | 0.90 | 1.00 | 1.10 | |
| A1 | 0.00 | 0.05 | 0.10 | |
| A2 | 0.70 | 0.85 | 1.00 | |
| A3 | 0.25 BSC | | | |
| b | 0.25 | 0.38 | 0.50 | |
| С | 0.10 | 0.18 | 0.26 | |
| D | 2.80 | 2.95 | 3.10 | |
| d | 0.30 REF | | | |
| Е | 2.50 | 2.75 | 3.00 | |
| E1 | 1.30 | 1.50 | 1.70 | |
| е | 0.95 BSC | | | |
| e1 | 1.90 BSC | | | |
| L1 | 0.60 REF | | | |
| L2 | 0.20 | 0.40 | 0.60 | |
| θ | 0° | | 10° | |
| | | | | |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code Μ

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

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